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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	e200z0h
Core Size	32-Bit Single-Core
Speed	64MHz
Connectivity	CANbus, I²C, LINbus, SCI, SPI
Peripherals	DMA, POR, PWM, WDT
Number of I/O	79
Program Memory Size	256KB (256K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	24K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 28x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/spc560b40l3b4e0x

List of tables

3.3 Voltage supply pins

Voltage supply pins are used to provide power to the device. Three dedicated VDD_LV/VSS_LV supply pairs are used for 1.2 V regulator stabilization.

Table 4. Voltage supply pin descriptions

Port pin	Function	Pin number			
		LQFP64	LQFP100	LQFP144	LBGA208(1)
VDD_HV	Digital supply voltage	7, 28, 56	15, 37, 70, 84	19, 51, 100, 123	C2, D9, E16, G13, H3, N9, R5
VSS_HV	Digital ground	6, 8, 26, 55	14, 16, 35, 69, 83	18, 20, 49, 99, 122	G7, G8, G9, G10, H1, H7, H8, H9, H10, J7, J8, J9, J10, K7, K8, K9, K10
VDD_LV	1.2V decoupling pins. Decoupling capacitor must be connected between these pins and the nearest V_{SS_LV} pin.(2)	11, 23, 57	19, 32, 85	23, 46, 124	D8, K4, P7
VSS_LV	1.2V decoupling pins. Decoupling capacitor must be connected between these pins and the nearest V_{DD_LV} pin.(2)	10, 24, 58	18, 33, 86	22, 47, 125	C8, J2, N7
VDD_BV	Internal regulator supply voltage	12	20	24	K3
VSS_HV_ADC	Reference ground and analog ground for the ADC	33	51	73	R15
VDD_HV_ADC	Reference voltage and analog supply for the ADC	34	52	74	P14

1. LBGA208 available only as development package for Nexus2+
2. A decoupling capacitor must be placed between each of the three VDD_LV/VSS_LV supply pairs to ensure stable voltage (see the recommended operating conditions in the device datasheet for details).

3.4 Pad types

In the device the following types of pads are available for system pins and functional port pins:

S = Slow(b)

M = Medium(b) (c)

F = Fast(b) (c)

I = Input only with analog feature(b)

J = Input/Output (‘S’ pad) with analog feature

X = Oscillator

b. See the I/O pad electrical characteristics in the device datasheet for details.

Table 6. Functional port pin descriptions

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number			
								LQFP64	LQFP100	LQFP144	LBGA208[3]
PA[0]	PCR[0]	AF0 AF1 AF2 AF3 —	GPIO[0] E0UC[0] CLKOUT — WKPU[19][4]	SIUL eMIOS_0 CGL — WKPU	I/O I/O O — I	M	Tristate	5	12	16	G4
PA[1]	PCR[1]	AF0 AF1 AF2 AF3 — —	GPIO[1] E0UC[1] — — NMI[5] WKPU[2][4]	SIUL eMIOS_0 — — WKPU WKPU	I/O I/O — — I I	S	Tristate	4	7	11	F3
PA[2]	PCR[2]	AF0 AF1 AF2 AF3 —	GPIO[2] E0UC[2] — — WKPU[3][4]	SIUL eMIOS_0 — — WKPU	I/O I/O — — I	S	Tristate	3	5	9	F2
PA[3]	PCR[3]	AF0 AF1 AF2 AF3 —	GPIO[3] E0UC[3] — — EIRQ[0]	SIUL eMIOS_0 — — SIUL	I/O I/O — — I	S	Tristate	43	68	90	K15
PA[4]	PCR[4]	AF0 AF1 AF2 AF3 —	GPIO[4] E0UC[4] — — WKPU[9][4]	SIUL eMIOS_0 — — WKPU	I/O I/O — — I	S	Tristate	20	29	43	N6
PA[5]	PCR[5]	AF0 AF1 AF2 AF3	GPIO[5] E0UC[5] — —	SIUL eMIOS_0 — —	I/O I/O — —	M	Tristate	51	79	118	C11
PA[6]	PCR[6]	AF0 AF1 AF2 AF3 —	GPIO[6] E0UC[6] — — EIRQ[1]	SIUL eMIOS_0 — — SIUL	I/O I/O — — I	S	Tristate	52	80	119	D11

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number			
								LQFP64	LQFP100	LQFP144	LBGA208[3]
PA[7]	PCR[7]	AF0 AF1 AF2 AF3 —	GPIO[7] E0UC[7] LIN3TX — EIRQ[2]	SIUL eMIOS_0 LINFlex_3 — SIUL	I/O I/O O — I	S	Tristate	44	71	104	D16
PA[8]	PCR[8]	AF0 AF1 AF2 AF3 — N/A[6] —	GPIO[8] E0UC[8] — — EIRQ[3] ABS[0] LIN3RX	SIUL eMIOS_0 — — SIUL BAM LINFlex_3	I/O I/O — — I I I	S	Input, weak pull-up	45	72	105	C16
PA[9]	PCR[9]	AF0 AF1 AF2 AF3 N/A[6]	GPIO[9] E0UC[9] — — FAB	SIUL eMIOS_0 — — BAM	I/O I/O — — I	S	Pull-down	46	73	106	C15
PA[10]	PCR[10]	AF0 AF1 AF2 AF3	GPIO[10] E0UC[10] SDA —	SIUL eMIOS_0 I2C_0 —	I/O I/O I/O —	S	Tristate	47	74	107	B16
PA[11]	PCR[11]	AF0 AF1 AF2 AF3	GPIO[11] E0UC[11] SCL —	SIUL eMIOS_0 I2C_0 —	I/O I/O I/O —	S	Tristate	48	75	108	B15
PA[12]	PCR[12]	AF0 AF1 AF2 AF3 —	GPIO[12] — — — SIN_0	SIUL — — — DSPI0	I/O — — — I	S	Tristate	22	31	45	T7
PA[13]	PCR[13]	AF0 AF1 AF2 AF3	GPIO[13] SOUT_0 — —	SIUL DSPI_0 — —	I/O O — —	M	Tristate	21	30	44	R7

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number			
								LQFP64	LQFP100	LQFP144	LBGA208[3]
PE[11]	PCR[75]	AF0 AF1 AF2 AF3 — —	GPIO[75] — CS4_1 — LIN3RX WKPU[14][4]	SIUL — DSPI_1 — LINFlex_3 WKPU	I/O — O — I I	S	Tristate	—	13	17	H2
PE[12]	PCR[76]	AF0 AF1 AF2 AF3 — —	GPIO[76] — E1UC[19][13] — SIN_2 EIRQ[11]	SIUL — eMIOS_1 — DSPI_2 SIUL	I/O — I/O — I I	S	Tristate	—	76	109	C14
PE[13]	PCR[77]	AF0 AF1 AF2 AF3	GPIO[77] SOUT2 E1UC[20] —	SIUL DSPI_2 eMIOS_1 —	I/O O I/O —	S	Tristate	—	—	103	D15
PE[14]	PCR[78]	AF0 AF1 AF2 AF3 —	GPIO[78] SCK_2 E1UC[21] — EIRQ[12]	SIUL DSPI_2 eMIOS_1 — SIUL	I/O I/O I/O — I	S	Tristate	—	—	112	C13
PE[15]	PCR[79]	AF0 AF1 AF2 AF3	GPIO[79] CS0_2 E1UC[22] —	SIUL DSPI_2 eMIOS_1 —	I/O I/O I/O —	M	Tristate	—	—	113	A13
PF[0]	PCR[80]	AF0 AF1 AF2 AF3 —	GPIO[80] E0UC[10] CS3_1 — ANS[8]	SIUL eMIOS_0 DSPI_1 — ADC	I/O I/O O — I	J	Tristate	—	—	55	N10
PF[1]	PCR[81]	AF0 AF1 AF2 AF3 —	GPIO[81] E0UC[11] CS4_1 — ANS[9]	SIUL eMIOS_0 DSPI_1 — I	I/O I/O O — I	J	Tristate	—	—	56	P10

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number			
								LQFP64	LQFP100	LQFP144	LBGA208[3]
PG[7]	PCR[103]	AF0 AF1 AF2 AF3	GPIO[103] E1UC[16] — —	SIUL eMIOS_1 — —	I/O I/O — —	M	Tristate	—	—	29	M1
PG[8]	PCR[104]	AF0 AF1 AF2 AF3 —	GPIO[104] E1UC[17] — CS0_2 EIRQ[15]	SIUL eMIOS_1 — DSPI_2 SIUL	I/O I/O — I/O I	S	Tristate	—	—	26	L2
PG[9]	PCR[105]	AF0 AF1 AF2 AF3	GPIO[105] E1UC[18] — SCK_2	SIUL eMIOS_1 — DSPI_2	I/O I/O — I/O	S	Tristate	—	—	25	L1
PG[10]	PCR[106]	AF0 AF1 AF2 AF3	GPIO[106] E0UC[24] — —	SIUL eMIOS_0 — —	I/O I/O — —	S	Tristate	—	—	114	D13
PG[11]	PCR[107]	AF0 AF1 AF2 AF3	GPIO[107] E0UC[25] — —	SIUL eMIOS_0 — —	I/O I/O — —	M	Tristate	—	—	115	B12
PG[12]	PCR[108]	AF0 AF1 AF2 AF3	GPIO[108] E0UC[26] — —	SIUL eMIOS_0 — —	I/O I/O — —	M	Tristate	—	—	92	K14
PG[13]	PCR[109]	AF0 AF1 AF2 AF3	GPIO[109] E0UC[27] — —	SIUL eMIOS_0 — —	I/O I/O — —	M	Tristate	—	—	91	K16
PG[14]	PCR[110]	AF0 AF1 AF2 AF3	GPIO[110] E1UC[0] — —	SIUL eMIOS_1 — —	I/O I/O — —	S	Tristate	—	—	110	B14

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number			
								LQFP64	LQFP100	LQFP144	LBGA208[3]
PH[7]	PCR[119]	AF0 AF1 AF2 AF3	GPIO[119] E1UC[9] CS3_2 MA[1]	SIUL eMIOS_1 DSPI_2 ADC	I/O I/O O O	M	Tristate	—	—	137	C5
PH[8]	PCR[120]	AF0 AF1 AF2 AF3	GPIO[120] E1UC[10] CS2_2 MA[0]	SIUL eMIOS_1 DSPI_2 ADC	I/O I/O O O	M	Tristate	—	—	138	A5
PH[9][9]	PCR[121]	AF0 AF1 AF2 AF3	GPIO[121] — TCK —	SIUL — JTAGC —	I/O — I —	S	Input, weak pull-up	60	88	127	B8
PH[10][9]	PCR[122]	AF0 AF1 AF2 AF3	GPIO[122] — TMS —	SIUL — JTAGC —	I/O — I —	S	Input, weak pull-up	53	81	120	B9

1. Alternate functions are chosen by setting the values of the PCR.PA bitfields inside the SIUL module. PCR.PA = 00 → AF0; PCR.PA = 01 → AF1; PCR.PA = 10 → AF2; PCR.PA = 11 → AF3. This is intended to select the output functions; to use one of the input functions, the PCR.IBE bit must be written to '1', regardless of the values selected in the PCR.PA bitfields. For this reason, the value corresponding to an input only function is reported as "—".
2. Multiple inputs are routed to all respective modules internally. The input of some modules must be configured by setting the values of the PSMIO.PADSELx bitfields inside the SIUL module.
3. LBGA208 available only as development package for Nexus2+
4. All WKPU pins also support external interrupt capability. See wakeup unit chapter for further details.
5. NMI has higher priority than alternate function. When NMI is selected, the PCR.AF field is ignored.
6. "Not applicable" because these functions are available only while the device is booting. Refer to BAM chapter of the reference manual for details.
7. Value of PCR.IBE bit must be 0
8. Be aware that this pad is used on the SPC560B64L3 and SPC560B64L5 to provide VDD_HV_ADC and VSS_HV_ADC1. Therefore, you should be careful in ensuring compatibility between SPC560B40x/50x and SPC560C40x/50x and SPC560B64.
9. Out of reset all the functional pins except PC[0:1] and PH[9:10] are available to the user as GPIO.
   PC[0:1] are available as JTAG pins (TDI and TDO respectively).
   PH[9:10] are available as JTAG pins (TCK and TMS respectively).
   If the user configures these JTAG pins in GPIO mode the device is no longer compliant with IEEE 1149.1-2001.
10. The TDO pad has been moved into the STANDBY domain in order to allow low-power debug handshaking in STANDBY mode. However, no pull-resistor is active on the TDO pad while in STANDBY mode. At this time the pad is configured as an input. When no debugger is connected the TDO pad is floating causing additional current consumption. To avoid the extra consumption TDO must be connected. An external pull-up resistor in the range of 47–100 kΩ should be added between the TDO pin and VDD_HV. Only in case the TDO pin is used as application pin and a pull-up cannot be used then a pull-down resistor with the same value should be used between TDO pin and GND instead.

11. Available only on SPC560Cx versions and SPC560B50B2 devices
12. Not available on SPC560B40L3 and SPC560B40L5 devices
13. Not available in 100 LQFP package
14. Available only on SPC560B50B2 devices
15. Not available on SPC560B44L3 devices

3.7 Nexus 2+ pins

In the LBGA208 package, eight additional debug pins are available (see *Table 7*).

Table 7. Nexus 2+ pin descriptions

Debug pin	Function	I/O direction	Pad type	Function after reset	Pin number		
					LQFP 100	LQFP 144	LBGA 208(1)
MCKO	Message clock out	O	F	—	—	—	T4
MDO0	Message data out 0	O	M	—	—	—	H15
MDO1	Message data out 1	O	M	—	—	—	H16
MDO2	Message data out 2	O	M	—	—	—	H14
MDO3	Message data out 3	O	M	—	—	—	H13
EVTI	Event in	I	M	Pull-up	—	—	K1
EVTO	Event out	O	M	—	—	—	L4
MSEO	Message start/end out	O	M	—	—	—	G16

1. LBGA208 available only as development package for Nexus2+.

3.8 Electrical characteristics

3.9 Introduction

This section contains electrical characteristics of the device as well as temperature and power considerations.

This product contains devices to protect the inputs against damage due to high static voltages. However, it is advisable to take precautions to avoid applying any voltage higher than the specified maximum rated voltages.

To enhance reliability, unused inputs can be driven to an appropriate logic voltage level (V_{DD} or V_{SS}). This could be done by the internal pull-up and pull-down, which is provided by the product for most general purpose pins.

The parameters listed in the following tables represent the characteristics of the device and its demands on the system.

In the tables where the device logic provides signals with their respective timing characteristics, the symbol “CC” for Controller Characteristics is included in the Symbol column.

Table 15. LQFP thermal characteristics(1) (continued)

Symbol		C	Parameter	Conditions(2)	Pin count	Value	Unit
$R_{\theta JC}$	CC	D	Thermal resistance, junction-to-case(5)	Single-layer board - 1s	64	11	°C/W
					100	22	
					144	22	
				Four-layer board - 2s2p	64	11	
					100	22	
					144	22	
Ψ_{JB}	CC	D	Junction-to-board thermal characterization parameter, natural convection	Single-layer board - 1s	64	TBD	°C/W
					100	33	
					144	34	
				Four-layer board - 2s2p	64	TBD	
					100	34	
					144	35	
Ψ_{JC}	CC	D	Junction-to-case thermal characterization parameter, natural convection	Single-layer board - 1s	64	TBD	°C/W
					100	9	
					144	10	
				Four-layer board - 2s2p	64	TBD	
					100	9	
					144	10	

1. Thermal characteristics are based on simulation.
2. V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C
3. Junction-to-ambient thermal resistance determined per JEDEC JESD51-3 and JESD51-6. Thermal test board meets JEDEC specification for this package.
4. Junction-to-board thermal resistance determined per JEDEC JESD51-8. Thermal test board meets JEDEC specification for the specified package.
5. Junction-to-case at the top of the package determined using MIL-STD 883 Method 1012.1. The cold plate temperature is used for the case temperature. Reported value includes the thermal resistance of the interface layer.

3.14.2 Power considerations

The average chip-junction temperature, T_J, in degrees Celsius, may be calculated using *Equation 1*:

Equation 1 $T_J = T_A + (P_D \times R_{\theta JA})$

Where:

T_A is the ambient temperature in °C.

$R_{\theta JA}$ is the package junction-to-ambient thermal resistance, in °C/W.

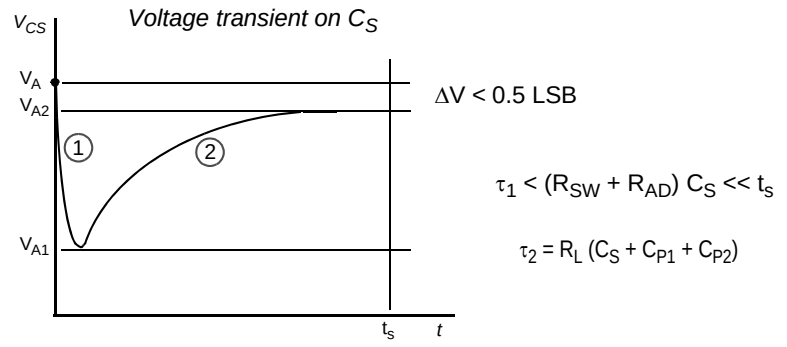
P_D is the sum of P_{INT} and $P_{I/O}$ ($P_D = P_{INT} + P_{I/O}$).

P_{INT} is the product of I_{DD} and V_{DD}, expressed in watts. This is the chip internal power.

$P_{I/O}$ represents the power dissipation on input and output pins; user determined.

A second aspect involving the capacitance network shall be considered. Assuming the three capacitances C_F, C_{P1} and C_{P2} are initially charged at the source voltage V_A (refer to the equivalent circuit in *Figure 19*): A charge sharing phenomenon is installed when the sampling phase is started (A/D switch close).

Figure 21. Transient behavior during sampling phase



In particular two different transient periods can be distinguished:

1. A first and quick charge transfer from the internal capacitance C_{P1} and C_{P2} to the sampling capacitance C_S occurs (C_S is supposed initially completely discharged): considering a worst case (since the time constant in reality would be faster) in which C_{P2} is reported in parallel to C_{P1} (call $C_P = C_{P1} + C_{P2}$), the two capacitances C_P and C_S are in series, and the time constant is

Equation 5

$$\tau_1 = (R_{SW} + R_{AD}) \bullet \frac{C_P \bullet C_S}{C_P + C_S}$$

Equation 5 can again be simplified considering only C_S as an additional worst condition. In reality, the transient is faster, but the A/D converter circuitry has been designed to be robust also in the very worst case: the sampling time t_s is always much longer than the internal time constant:

Equation 6

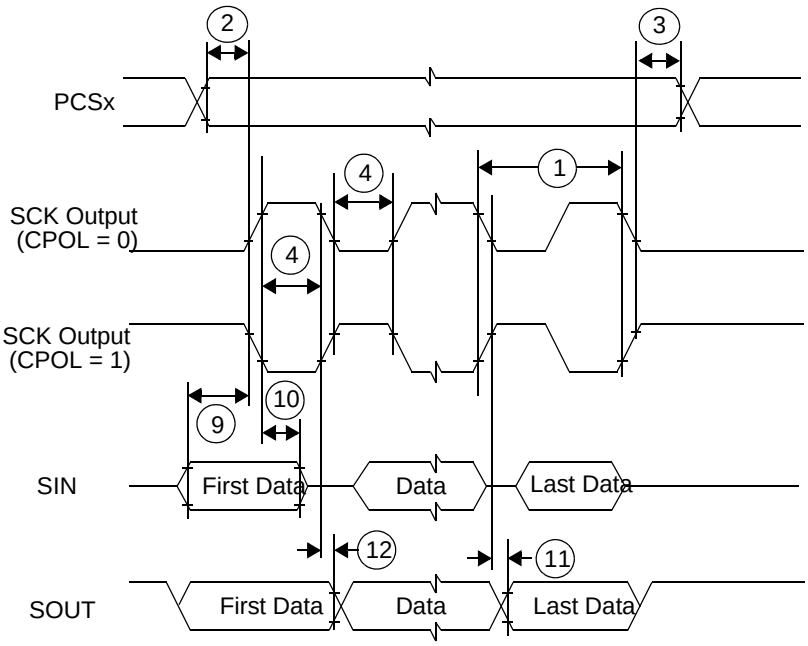
$$\tau_1 < (R_{SW} + R_{AD}) \bullet C_S \ll t_S$$

The charge of C_{P1} and C_{P2} is redistributed also on C_S, determining a new value of the voltage V_{A1} on the capacitance according to *Equation 7*:

Table 47. DSPI characteristics[1]

No.	Symbol		C	Parameter		DSPI0/DSPI1			DSPI2			Unit
						Min	Typ	Max	Min	Typ	Max	
1	t_{SCK}	SR	D	SCK cycle time	Master mode (MTFE = 0)	125	—	—	333	—	—	ns
			D		Slave mode (MTFE = 0)	125	—	—	333	—	—	
			D		Master mode (MTFE = 1)	83	—	—	125	—	—	
			D		Slave mode (MTFE = 1)	83	—	—	125	—	—	
—	f_{DSPI}	SR	D	DSPI digital controller frequency		—	—	f_{CPU}	—	—	f_{CPU}	MHz
—	Δt_{CSC}	CC	D	Internal delay between pad associated to SCK and pad associated to CSn in master mode for CSn1→0	Master mode	—	—	130[2]	—	—	15[3]	ns
—	Δt_{ASC}	CC	D	Internal delay between pad associated to SCK and pad associated to CSn in master mode for CSn1→1	Master mode	—	—	130[3]	—	—	130[3]	ns
2	t_{CSCext}[4]	SR	D	CS to SCK delay	Slave mode	32	—	—	32	—	—	ns
3	t_{ASCext}[5]	SR	D	After SCK delay	Slave mode	$1/f_{DSPI} + 5$	—	—	$1/f_{DSPI} + 5$	—	—	ns
4	t_{SDC}	CC	D	SCK duty cycle	Master mode	—	$t_{SCK/2}$	—	—	$t_{SCK/2}$	—	ns
		SR	D		Slave mode	$t_{SCK/2}$	—	—	$t_{SCK/2}$	—	—	
5	t_A	SR	D	Slave access time	Slave mode	—	—	$1/f_{DSPI} + 70$	—	—	$1/f_{DSPI} + 130$	ns
6	t_{DI}	SR	D	Slave SOUT disable time	Slave mode	7	—	—	7	—	—	ns
7	t_{PCSC}	SR	D	PCSx to $\overline{\text{PCSS}}$ time		0	—	—	0	—	—	ns
8	t_{PASC}	SR	D	$\overline{\text{PCSS}}$ to PCSx time		0	—	—	0	—	—	ns

Figure 23. DSPI classic SPI timing – master, CPHA = 0



Note: Numbers shown reference *Table 47*.

Figure 28. DSPI modified transfer format timing – master, CPHA = 1

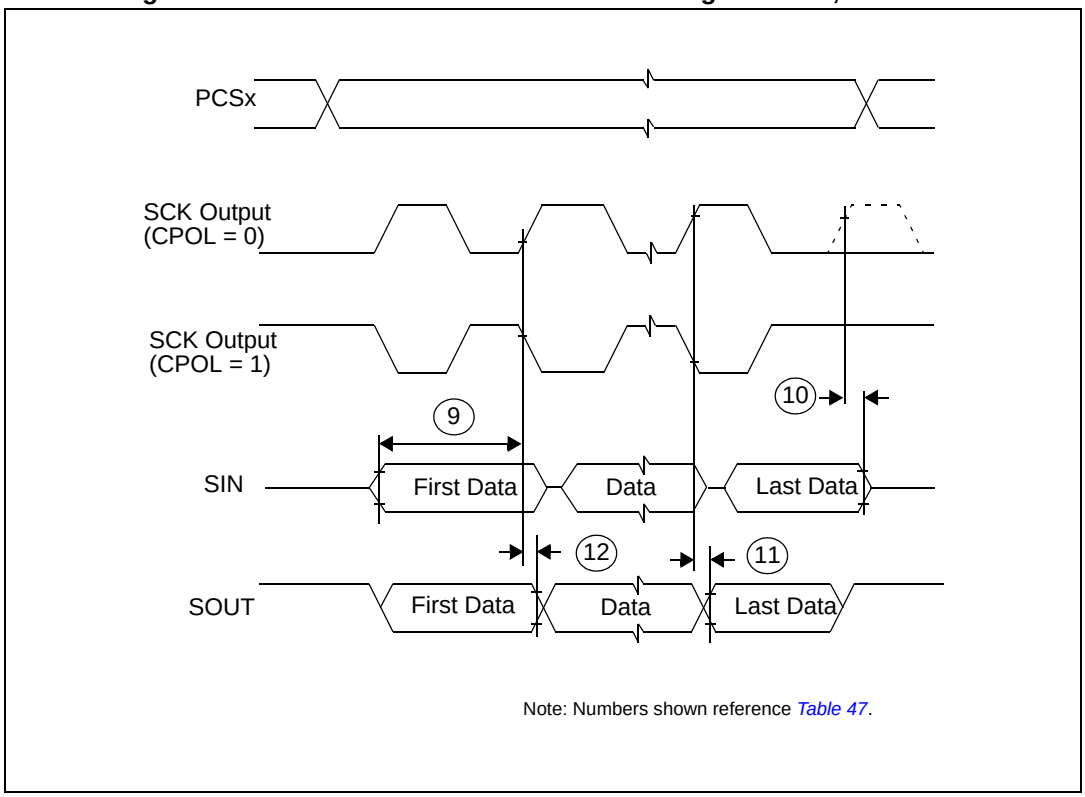


Figure 29. DSPI modified transfer format timing – slave, CPHA = 0

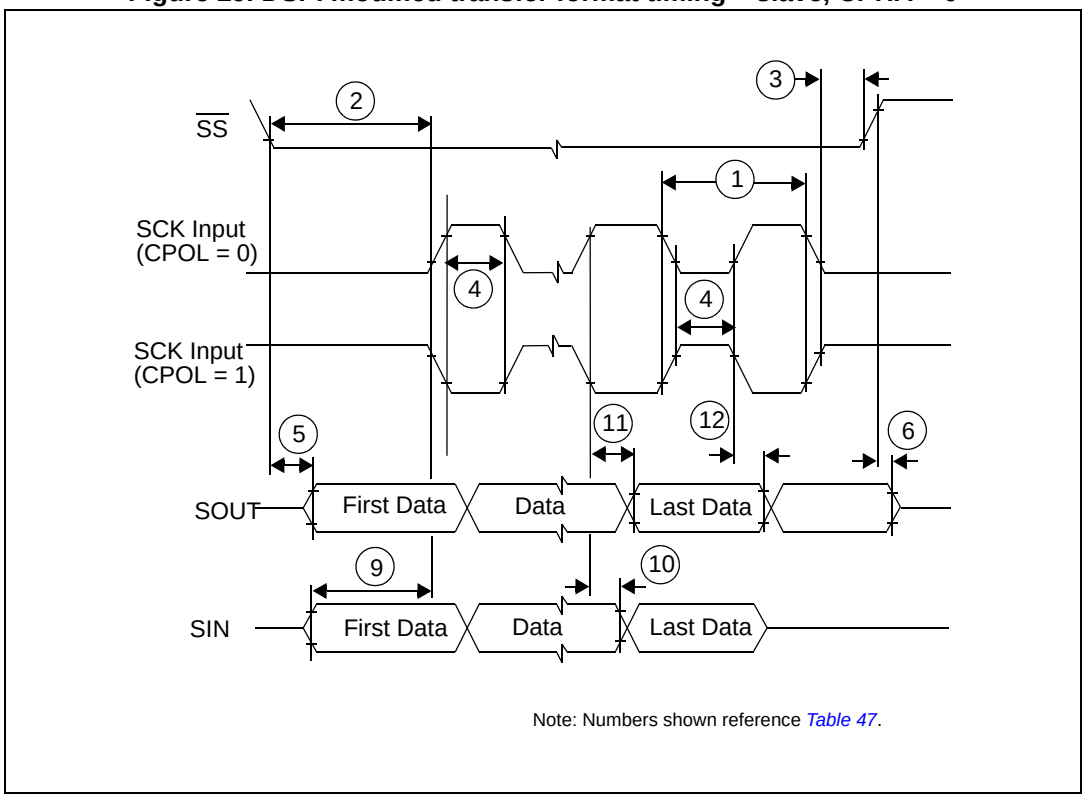
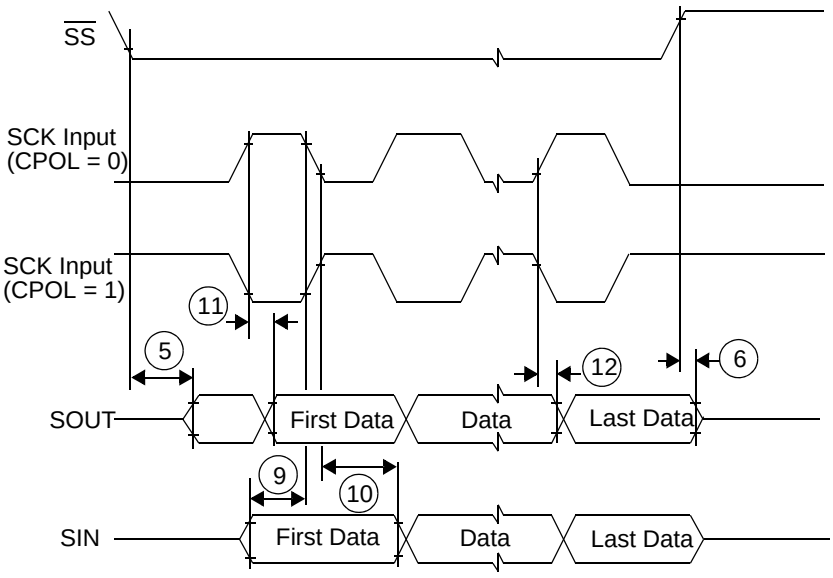
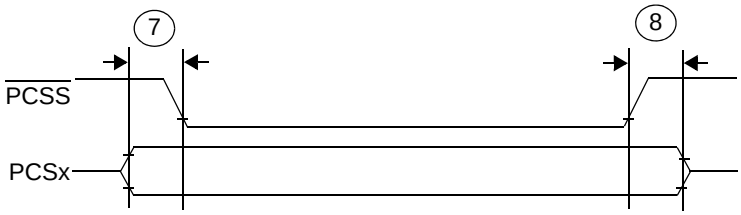


Figure 30. DSPI modified transfer format timing – slave, CPHA = 1



Note: Numbers shown reference *Table 47*.

Figure 31. DSPI PCS strobe ($\overline{\text{PCSS}}$) timing



Note: Numbers shown reference *Table 47*.

3.27.3 Nexus characteristics

Table 48. Nexus characteristics

No.	Symbol		C	Parameter	Value			Unit
					Min	Typ	Max	
1	t_{TCYC}	CC	D	TCK cycle time	64	—	—	ns
2	t_{MCYC}	CC	D	MCKO cycle time	32	—	—	ns
3	t_{MDOV}	CC	D	MCKO low to MDO data valid	—	—	8	ns

4 Package characteristics

4.1 ECOPACK®

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK® is an ST trademark.

4.2 Package mechanical data

4.2.1 LQFP64

Figure 34. LQFP64 package mechanical drawing

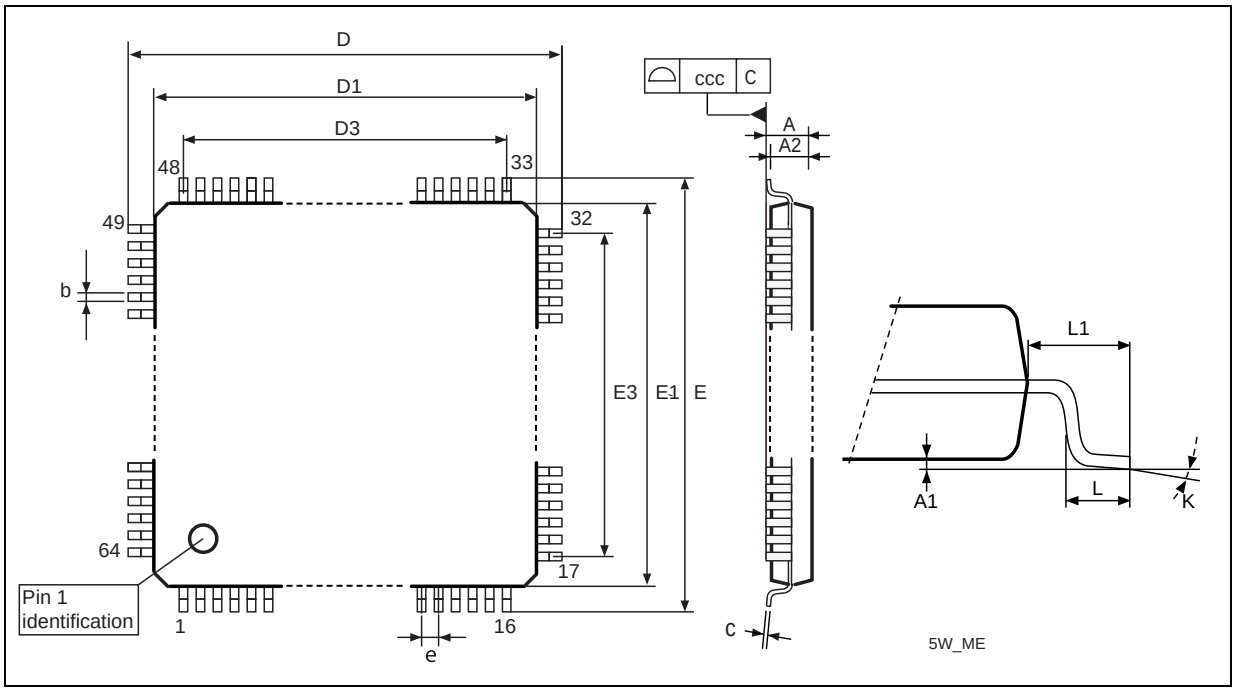


Table 50. LQFP64 mechanical data

Symbol	mm			inches(1)		
	Min	Typ	Max	Min	Typ	Max
A	—	—	1.6	—	—	0.063
A1	0.05	—	0.15	0.002	—	0.0059
A2	1.35	1.4	1.45	0.0531	0.0551	0.0571
b	0.17	0.22	0.27	0.0067	0.0087	0.0106
c	0.09	—	0.2	0.0035	—	0.0079
D	11.8	12	12.2	0.4646	0.4724	0.4803

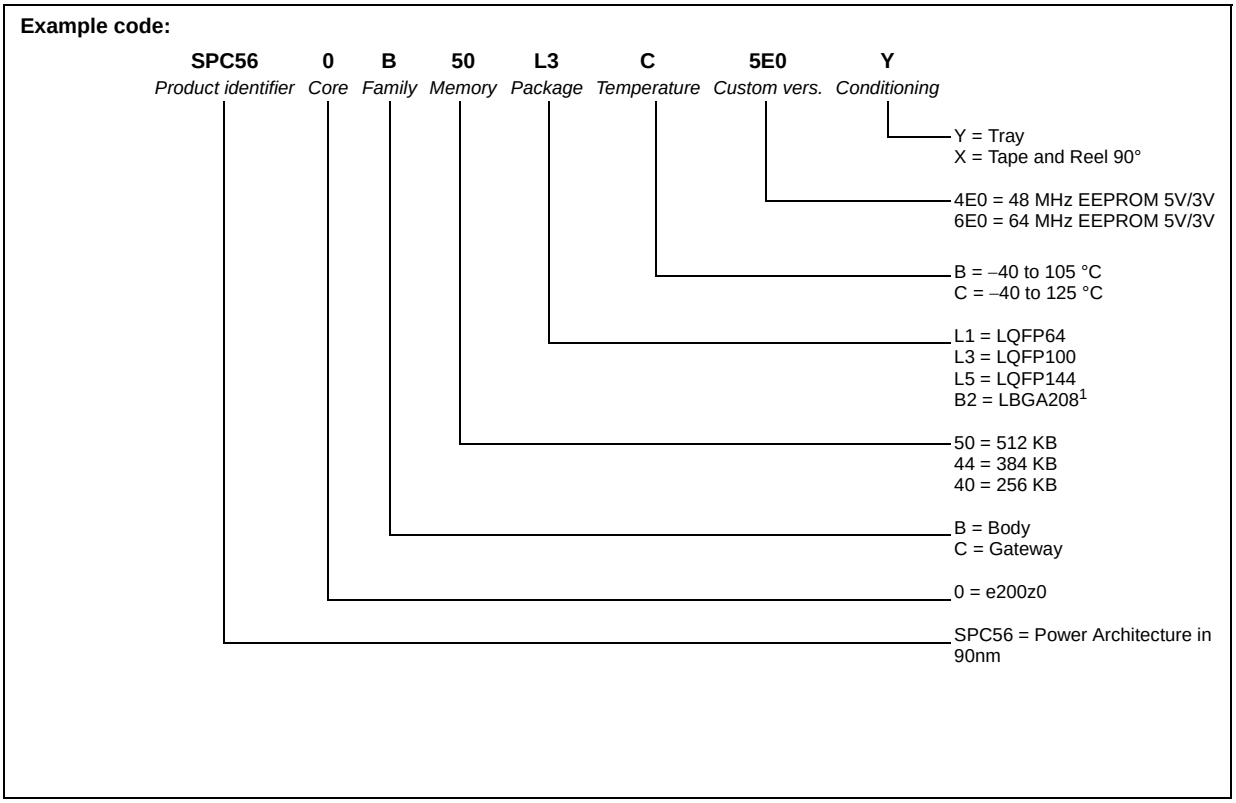
Table 50. LQFP64 mechanical data (continued)

Symbol	mm			inches[1]		
	Min	Typ	Max	Min	Typ	Max
D1	9.8	10	10.2	0.3858	0.3937	0.4016
D3	—	7.5	—	—	0.2953	—
E	11.8	12	12.2	0.4646	0.4724	0.4803
E1	9.8	10	10.2	0.3858	0.3937	0.4016
E3	—	7.5	—	—	0.2953	—
e	—	0.5	—	—	0.0197	—
L	0.45	0.6	0.75	0.0177	0.0236	0.0295
L1	—	1	—	—	0.0394	—
k	0.0°	3.5°	7.0°	0.0°	3.5°	7.0°
ccc	—	—	0.08	—	—	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

5 Ordering information

Figure 38. Commercial product code structure



1. LBGA208 available only as development package for Nexus2+

Table 55. Document revision history (continued)

Date	Revision	Changes
06-Mar-2009	2 (continued)	Updated tables: – “I/O input DC electrical characteristics” – “I/O pull-up/pull-down DC electrical characteristics” – “SLOW configuration output buffer electrical characteristics” – “MEDIUM configuration output buffer electrical characteristics” – “FAST configuration output buffer electrical characteristics” Added “Output pin transition times” section Updated “I/O consumption” table Updated “Start-up reset requirements” figure Updated “Reset electrical characteristics” table “Voltage regulator electrical characteristics” section: – Amended description of LV_PLL “Voltage regulator capacitance connection” figure: – Exchanged position of symbols C_{DEC1} and C_{DEC2} Updated tables” – “Voltage regulator electrical characteristics” – “Low voltage monitor electrical characteristics” – “Low voltage power domain electrical characteristics” Added “Low voltage monitor vs reset” figure Updated “Flash memory electrical characteristics” section Added “Electromagnetic compatibility (EMC) characteristics” section Updated “Fast external crystal oscillator (4 to 16 MHz) electrical characteristics” section Updated “Slow external crystal oscillator (32 kHz) electrical characteristics” section Updated tables: – “FMPLL electrical characteristics” – “Fast internal RC oscillator (16 MHz) electrical characteristics” – “Slow internal RC oscillator (128 kHz) electrical characteristics” Added “On-chip peripherals” section Added “ADC input leakage current” table Updated “ADC conversion characteristics” table Updated “ECOPACK®” section Corrected inverted column headings for typical and minimum dimensions in “LQFP64 mechanical data” and “LQFP100 mechanical data” tables Added “Abbrevation” appendix
03-Jun-2009	3	Corrected “Commercial product code structure” figure

Table 55. Document revision history (continued)

Date	Revision	Changes
22-Jul-2010	7	**Changes between revisions 5 and 7** Added LQFP64 package information Updated the “Features“ section. Section “Introduction” – Relocated a note Table: “SPC560B40x/50x and SPC560C40x/50x device comparison“ – Added footnote regarding SCI and CAN Added eDMA block in the “SPC560B40x/50x and SPC560C40x/50x series block diagram” figure Removed alternate function information from “LQFP 100-pin configuration” and “LQFP 100-pin configuration” figures. Added “Functional port pin descriptions” table Deleted the “NVUSRO[WATCHDOG_EN] field description“ section Table: “Absolute maximum ratings“ – Removed the min value of V_{IN} relative tio V_{DD} Table ”Recommended operating conditions (3.3 V)” – TV_{DD}: made single row ”Recommended operating conditions (5.0 V)” – deleted $T_{A\ C\text{-}Grade\ Part}$, $T_{J\ C\text{-}Grade\ Part}$, $T_{A\ V\text{-}Grade\ Part}$, $T_{J\ V\text{-}Grade\ Part}$, $T_{A\ M\text{-}Grade\ Part}$, $T_{J\ M\text{-}Grade\ Part}$ rows Table: “LQFP thermal characteristics” – Added more rows – Rounded the values Removed table “LBGA208 thermal characteristics” Table “I/O input DC electrical characteristics” – W_{FI}: insered a footnote – W_{NFI}: insered a footnote Table “I/O consuption“ – Removed I_{DYNSEG} row – Added “I/O weight “ table Replaced “$\overline{\text{nRSTIN}}$” with “$\overline{\text{RESET}}$” in the “$\overline{\text{RESET}}$ electrical characteristics” section. Table “Voltage regulator electrical characteristics“ – Updated the values – Removed $I_{VREGREF}$ and $I_{VREDLVD12}$ – Added a note about I_{DD_BC} Table: “Low voltage monitor electrical characteristics“ – changed min value$V_{LVDHV3L}$, from 2.7 to 2.6 – Inserted max value of $V_{LVDLVCORL}$ – Updated V_{PORH} values – Updated $V_{LVDLVCORL}$ value Table “Low voltage power domain electrical characteristics“ – Entirely updated Table “Program and erase specifications“ – Inserted T_{eslat} row Table “Flash power supply DC electrical characteristics“ – Entirely updated

Table 55. Document revision history (continued)

Date	Revision	Changes
01-Oct-2011	9	Formatting and minor editorial changes throughout Harmonized oscillator nomenclature Device summary table: removed 384 KB code flash device versions Device comparison table: changed temperature value in footnote 2 from 105 °C to 125 °C; removed 384 KB code flash device versions LQFP 64-pin configuration: renamed pin 6 from VPP_TEST to VSS_HV Removed “Pin Muxing” section; added sections “Pad configuration during reset phases”, “Voltage supply pins”, “Pad types”, “System pins,” “Functional ports”, and “Nexus 2+ pins” Section “NVUSRO register”: edited content to separate configuration into electrical parameters and digital functionality; updated footnote describing default value of ‘1’ in field descriptions NVUSRO[PAD3V5V] and NVUSRO[OSCILLATOR_MARGIN] Added section “NVUSRO[WATCHDOG_EN] field description” Recommended operating conditions (3.3 V) and Recommended operating conditions (5.0 V): updated conditions for ambient and junction temperature characteristics I/O input DC electrical characteristics: updated I_{LKG} characteristics Section “I/O pad current specification”: removed content referencing the I_{DYNSEG} maximum value I/O consumption: replaced instances of “Root medium square” with “Root mean square” I/O weight: replaced instances of bit “SRE” with “SRC”; added pads PH[9] and PH[10]; added supply segments; removed weight values in 64-pin LQFP for pads that do not exist in that package Reset electrical characteristics: updated parameter classification for $\|I_{WPU}\|$ Updated Voltage regulator electrical characteristics Section “Low voltage detector electrical characteristics”: changed title (was “Voltage monitor electrical characteristics”); added event status flag names found in RGM chapter of device reference manual to POR module and LVD descriptions; replaced instances of “Low voltage monitor” with “Low voltage detector”; updated values for $V_{LVDLVBKPL}$ and $V_{LVDLVCORL}$; replaced “LVD_DIGBKP” with “LVDLVBKP” in note Updated section “Power consumption” Fast external crystal oscillator (4 to 16 MHz) electrical characteristics: updated parameter classification for $V_{FXOSCOP}$ Crystal oscillator and resonator connection scheme: added footnote about possibility of adding a series resistor Slow external crystal oscillator (32 kHz) electrical characteristics: updated footnote 1 FMPLL electrical characteristics: added short term jitter characteristics; inserted “—” in empty min value cell of t_{lock} row Section “Input impedance and ADC accuracy”: changed “V_A/V_{A2}” to “V_{A2}/V_A” in Equation 11 ADC input leakage current: updated I_{LKG} characteristics ADC conversion characteristics: updated symbols On-chip peripherals current consumption: changed “supply current on “$V_{DD\_HV\_ADC}$” to “supply current on” V_{DD_HV}” in $I_{DD\_HV(FLASH)}$ row; updated $I_{DD\_HV(PLL)}$ value—was 3 * f_{periph}, is 30 * f_{periph}; updated footnotes DSPI characteristics: added rows t_{PCSC} and t_{PASC} Added DSPI PCS strobe (PCSS) timing diagram Updated order codes.
17-Jan-2013	10	Internal review.